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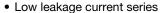
Vishay Semiconductors

Power Silicon Rectifier Diodes, (Stud Version), 35 A, 40 A, 60 A



DO-5 (DO-203AB)

FEATURES





Good surge current capability up to 1000 A

RoHS

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

A, 40 A, 60 A
-5 (DO-203AB)
Single

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS
1		35 ⁽¹⁾	35 ⁽¹⁾	40 ⁽¹⁾	60 ⁽¹⁾	Α
I _{F(AV)}	T _C	140 ⁽¹⁾	140 ⁽¹⁾	150 ⁽¹⁾	140 ⁽¹⁾	°C
1	50 Hz	480	380	765	860	^
IFSM	60 Hz	500 ⁽¹⁾	400 ⁽¹⁾	800 ⁽¹⁾	900 (1)	Α
I ² t	50 Hz	1140	730	2900	3700	A ² s
I-T	60 Hz	1040	670	2650	3400	A-S
I ² √t		16 100	10 300	41 000	52 500	A ² √s
V _{RRM}	Range	50 to 600 ⁽¹⁾	700 to 1000 ⁽¹⁾	50 to 600 ⁽¹⁾	50 to 600 ⁽¹⁾	V
TJ		-65 to +200	-65 to +200	-65 to +200	-65 to +200	°C

Note

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	3		V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = -65 °C to +200 °C ⁽²⁾) V	V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _J = -65 °C to +200 °C ⁽²⁾) V	
VS-1N1183	VS-1N1183A	VS-1N2128A	50 ⁽¹⁾	50 ⁽¹⁾	
VS-1N1184	VS-1N1184A	VS-1N2129A	100 (1)	100 (1)	
VS-1N1185	VS-1N1185A	VS-1N2130A	150 ⁽¹⁾	150 ⁽¹⁾	
VS-1N1186	VS-1N1186A	VS-1N2131A	200 (1)	200 (1)	
VS-1N1187	VS-1N1187A	VS-1N2133A	300 (1)	300 ⁽¹⁾	
VS-1N1188	VS-1N1188A	VS-1N2135A	400 (1)	400 (1)	
VS-1N1189	VS-1N1189A	VS-1N2137A	500 ⁽¹⁾	500 ⁽¹⁾	
VS-1N1190	VS-1N1190A	VS-1N2138A	600 ⁽¹⁾	600 ⁽¹⁾	
VS-1N3765	VS-1N2160		700 (1)	700 ⁽¹⁾	
VS-1N3766			800 (1)	800 (1)	
VS-1N3767			900 (1)	900 (1)	
VS-1N3768			1000 (1)	1000 (1)	

Notes

⁽¹⁾ JEDEC® registered values

Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA
JEDEC® registered values

 $^{^{(2)}}$ For 1N1183 Series and 1N3765 Series T_C = -65 $^{\circ}$ C to +190 $^{\circ}$ C



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PARAMETER	SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	1-phase operation, 180° sinusoidal conduction		35 ⁽¹⁾ 140 ⁽¹⁾	35 ⁽¹⁾ 140 ⁽¹⁾	40 ⁽¹⁾ 150 ⁽¹⁾	60 ⁽¹⁾	A °C
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load	480	380	765	860	
Maximum peak one cycle	1	Half cycle 60 Hz sine wave or 5 ms rectangular pulse	condition and with rated V _{RRM} applied	500 ⁽¹⁾	400 (1)	800 (1)	900 (1)	
non-repetitive surge current	I _{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and	570	455	910	1000	А
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse	with $\frac{1}{2}$ V_{RRM} applied following surge = 0	595	475	950	1050	
		t = 10 ms	With rated V _{RRM}	1140	730	2900	3700	
Maximum I ² t for fusing	– I ² t	t = 8.3 ms	applied following surge, initial $T_J = T_J$ maximum	1040	670	2650	3400	A ² s
		t = 10 ms	With V _{RRM} = 0 following surge, initial T _J = T _J maximum	1610	1030	4150	5250	A ² S
Maximum I ² t for individual device fusing		t = 8.3 ms		1470	940	3750	4750	
Maximum l ² √t for individual device fusing	I²√t (2)	t = 0.1 to 10 ms, V _{RRM} = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage	V _{FM}	T _J = 25 °C		1.7 ⁽¹⁾	1.8 ⁽¹⁾	1.3 ⁽¹⁾	1.3 ⁽¹⁾	V
at maximum forward current (I _{FM})				110	110	126	188	Α
$V_{RRM} = 700$				-	5.0 ⁽¹⁾	-	-	
Maximum avorago		Maximum rated I _{F0}	wa and To	-	4.0 ⁽¹⁾	-	-	
Maximum average reverse current $V_{RRM} = 900$	I _{R(AV)}	maximum ratou i _{F()}	-	3.0 (1)	-	-	mA	
V _{RRM} = 1000				-	2.0 (1)	-	-	
		Maximum rated IF($_{AV)}$, V_{RRM} and T_{C}	10 ⁽¹⁾	-	2.5 ⁽¹⁾	10 ⁽¹⁾	

Notes

(1) JEDEC® registered values

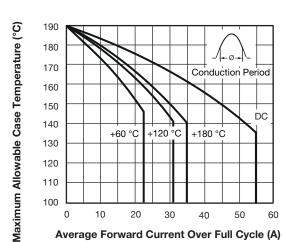
(2) I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS 1N1183 1N3765 1		1N1183A	1N2128A	UNITS	
Maximum operating case temperature range	T _C		-65 to +190 ⁽¹⁾ -65 to +200		+200	°C	
Maximum storage temperature range	T _{Stg}		-65 to	-65 to +175 ⁽¹⁾ -65 to +200		+200	
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	1.0	1.00 (1) 1.1 (1)		0.65 (1)	°C/W
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		C/VV		
		Not lubricated thread, tighting on nut (2)	3.4 (30)				
Maximum allowable		Lubricated thread, tighting on nut (2)		2.3	3 (20)		N·m
mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon (3)	4.2 (37)			(lbf · in)	
(Lubricated thread, tighting on hexagon (3)		3.2	2 (28)		
Annyayimata waisht			17			g	
Approximate weight					0.6		oz.
Case style		JEDEC®		DO	-5 (DO-203	AB)	

Notes

- (1) JEDEC registered values®
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

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Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

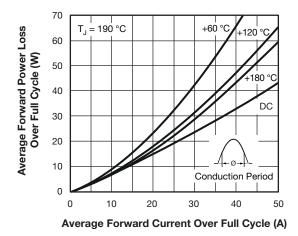


Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

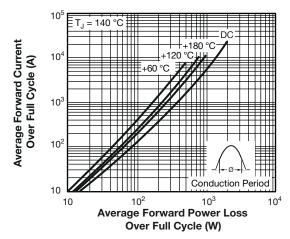


Fig. 3 - Typical High Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

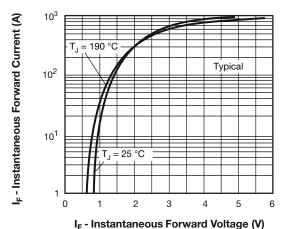


Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series

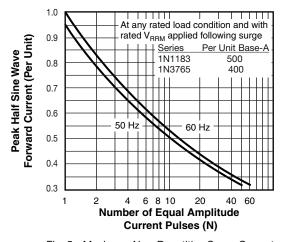
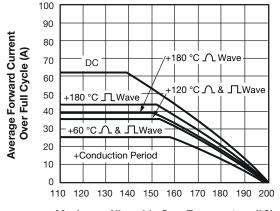


Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series



Maximum Allowable CaseTemperature (°C)

Fig. 6 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N1183A Series



1.0

0.9

0.8

0.7

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Per Unit Base-A

At any rated load condition and with

rated V_{BBM} applied following surge

↓ Series

1N1183A

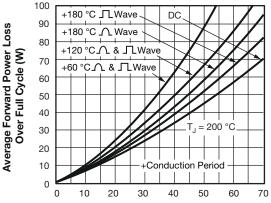
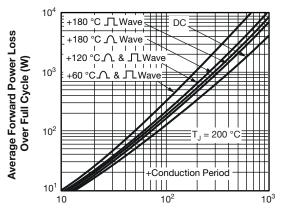


Fig. 7 - Maximum Low Level Forward Power Loss vs.

Maximum Peak Half Sine Wave Forward Current (Per Unit) 0.6 50 H 0.4 0.3 8 10 **Number of Equal Amplitude** Average Forward Current Over Full Cycle (A) **Current Pulses (N)** Fig. 10 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183A Series Average Forward Current, 1N1183A Series



Average Forward Current Over Full Cycle (A)

Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

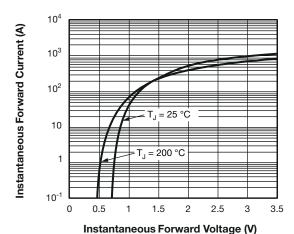


Fig. 9 - Maximum Forward Voltage vs. Forward Current, 1N1183A Series

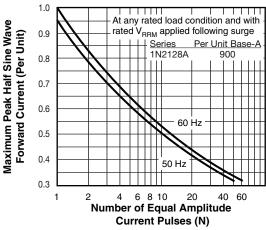


Fig. 11 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N2128A Series

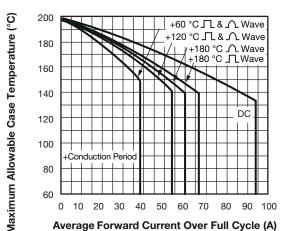


Fig. 12 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N2128A Series

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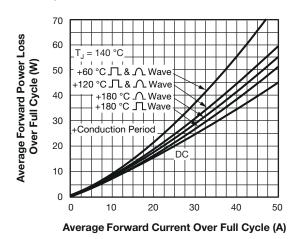
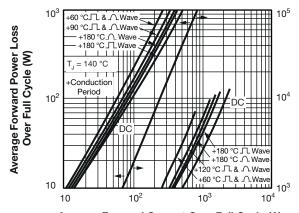


Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

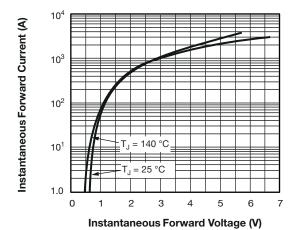


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

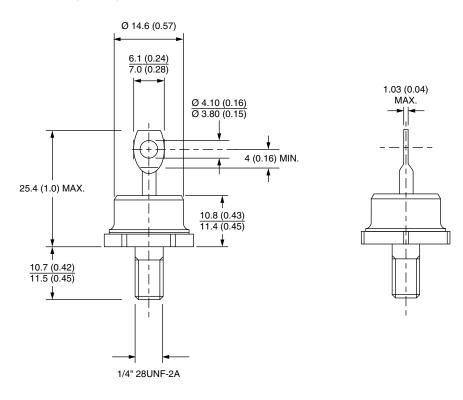
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95360				

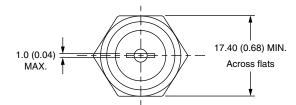


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DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)







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